NSN 5962-00-163-6293

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View Online at https://aerobasegroup.com/nsn/5962-00-163-6293 **Body Length:** Between 0.660 inches and 0.785 inches **Body Width:** Between 0.220 inches and 0.280 inches **Body Height:** Between 0.140 inches and 0.185 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:**

6 input

Case Outline Source And Designator:

T0-116 joint electron device engineering council

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

40.0 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Diode matrix

Precious Material And Location:

Terminal surface gold

Precious Material:

Gold

Terminal Type And Quantity:

14 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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